



Genesys Logic, Inc.

GL3227

**USB 3.2 GEN1 to SD 4.0
Memory Card Reader Controller**

Datasheet

**Revision 1.10
Jul. 07, 2020**

Copyright

Copyright © 2020 Genesys Logic, Inc. All rights reserved. No part of the materials shall be reproduced in any form or by any means without prior written consent of Genesys Logic, Inc.

Ownership and Title

Genesys Logic, Inc. owns and retains of its right, title and interest in and to all materials provided herein. Genesys Logic, Inc. reserves all rights, including, but not limited to, all patent rights, trademarks, copyrights and any other propriety rights. No license is granted hereunder.

Disclaimer

All Materials are provided “as is”. Genesys Logic, Inc. makes no warranties, express, implied or otherwise, regarding their accuracy, merchantability, fitness for any particular purpose, and non-infringement of intellectual property. In no event shall Genesys Logic, Inc. be liable for any damages, including, without limitation, any direct, indirect, consequential, or incidental damages. The materials may contain errors or omissions. Genesys Logic, Inc. may make changes to the materials or to the products described herein at anytime without notice.

Genesys Logic, Inc.

13F., No. 205, Sec. 3, Beixin Rd., Xindian Dist. 231,

New Taipei City, Taiwan

Tel : (886-2) 8913-1888

Fax : (886-2) 6629-6168

<http://www.genesyslogic.com>

Revision History

Revision	Date	Description
1.00	06/22/2016	Formal release
1.01	03/08/2017	Rename USB 3.0 to USB 3.1 GEN 1 Update CH3.2 Pin Description, p.9
1.02	04/19/2017	Update CH3.1 QFN 48 Pinout
1.03	05/08/2017	Update CH3.2 Pin Description
1.04	07/18/2017	Update CH3.2 Pin Description
1.05	02/21/2018	Update Table 3.1 - Pin Description
1.06	01/11/2019	Update CH2 Features
1.07	07/10/2019	1. Update CH5.3 DC Characteristics 2. Add CH5.5 IC ESD/LU Level 3. Add CH5.6 Thermal information
1.08	11/06/2019	Update Table 6.1 - SPI NOR Flash Support List
1.09	04/09/2020	Update Table 5.3 - DC Characteristics
1.10	07/07/2020	Update Table 6.1 - SPI NOR Flash Support List

Table of Contents

CHAPTER 1 GENERAL DESCRIPTION	6
CHAPTER 2 FEATURES.....	7
CHAPTER 3 Pin Assignment	8
3.1 QFN 48 Pinout	8
3.2 Pin Description.....	9
CHAPTER 4 Block Diagram	11
4.1 Super Speed and HS PHY	11
4.2 USB Controller	11
4.3 EPFIFO	11
4.4 MCU.....	12
4.5 MHE (Media Hardware Engine)	12
4.6 Regulator	12
4.7 DC-DC	12
4.8 UHS-II PHY	12
CHAPTER 5 ELECTRICAL CHARACTERISTICS.....	13
5.1 Temperature Conditions.....	13
5.2 Operating Conditions.....	13
5.3 DC Characteristics	13
5.4 AC Characteristics of Reset Timing	14
5.4.1 Reset Timing.....	14
5.4.2 SD Card Clock Frequency	15
5.5 IC ESD/LU Level.....	15
5.6 Thermal information.....	16
CHAPTER 6 SPI NOR Flash Support List.....	17
CHAPTER 7 Package Dimension	18
CHAPTER 8 ORDERING INFORMATION	19

List of Figures

Figure 3.1 - QFN 48 Pinout Diagram	8
Figure 4.1 - Functional Block Diagram.....	11
Figure 5.1 - Timing Diagram of Reset Width	14
Figure 5.2 - Timing Diagram of Power-on to USB Bus Ready	14
Figure 7.1 - QFN 48 Pin Package.....	18

List of Tables

Table 3.1 - Pin Description	9
Table 5.1 - Temperature Conditions	13
Table 5.2 - Operating Conditions.....	13
Table 5.3 - DC Characteristics	13
Table 5.4 - Reset Timing	15
Table 5.5 - SD Card Clock Frequency.....	15
Table 5.6 - IC ESD/LU Level.....	15
Table 5.7 - Thermal information (QFN48)	16
Table 6.1 - SPI NOR Flash Support List.....	17
Table 8.1 - Ordering Information.....	19

CHAPTER 1 GENERAL DESCRIPTION

GL3227 is an USB 3.1 GEN1 to SD4.0 Single LUN Memory Card Reader Controller.

GL3227 supports various types of SD memory cards, such as Secure Digital™ (SD), SDHC, miniSD and microSD (T-Flash), MultiMediaCard™ (MMC), RS-MMC, MMCmicro and MMCmobile. It also supports high density memory cards (Capacity up to 2TB), such as SDXC, ultra high speed memory cards, SD3.0 UHS-I and the latest generation high speed memory cards SD4.0 UHS-II card.

The GL3227 integrates a high speed 8051 microprocessor and a high efficiency hardware engine for the best data transfer performance between USB and various memory card interfaces. It supports ISP (In System Programming) for firmware upgrade from the external SPI Flash via USB port. It integrates 5V to 3.3V and 3.3V to 1.2V regulators and power MOSFETs which can reduce system BOM cost. It also integrates 5V to 1.2V DC-DC as alternative to improve the power efficiency.

CHAPTER 2 FEATURES

- USB specification compliance
 - Comply with Universal Serial Bus 3.1 Specification (USB 3.1 GEN1)
 - Comply with Universal Serial Bus Specification rev. 2.0 (USB 2.0)
 - Comply with USB Mass Storage Class Specification rev. 1.0
 - Support USB Mass Storage Class Bulk-Only Transport (BOT)
 - Support 1 device address and up to 3 endpoints: Control (0) / Bulk Data Read In (1) / Bulk Data Write Out (2)
 - Support 5 Gbps/SuperSpeed, 480 Mbps/high-speed, and 12 Mbps/full-speed transfer rates
- Integrated USB building blocks
 - SuperSpeed USB/USB 2.0 transceiver macro (UTM), Serial Interface Engine (SIE), and embedded Power-On Reset (POR)
- Embedded high speed 8051 micro-controller
- High efficiency hardware DMA engine improves data transfer performance between USB and flash card interfaces
- Support Secure Digital™ v1.0 / v1.1 / v2.0/ SDHC / SDXC (capacity up to 2TB)
- Support Secure Digital™ v3.0 UHS-I (Ultra High Speed): SDR12/SDR25/SDR50/DDR50/SDR104
- Support Secure Digital™ v4.0 UHS-II: Full Duplex Mode and Half Duplex Mode
- Support Secure Digital™ v5.0
- Support MultiMediaCard™ (MMC)
 - MMC specification v3.x / v4.0 / v4.1 / v4.2 / v4.3 / v4.4
 - x1 / x4 bit data bus
- Support HUAWEI Nano Memory Card
- Support ISP (In System Programming) for firmware upgrade from the external SPI Flash via USB port
- On-Chip power MOSFETs for supplying flash media card power
- On-chip 5V to 3.3V and 3.3V to 1.2V regulator
- On-chip 5V to 1.2V DC-DC to improve power efficiency.
- Support Over-Current protection mechanism
- Support USB 2.0 LPM (Link Power Management)
- Support USB 3.1 GEN1 LTM (Latency Tolerance Messaging)
- Support USB 3.1 GEN1 U1/U2/U3 low power link state
- Pass the USB-IF Test Procedure for SuperSpeed product (TID: 340970004)
- Support Latency Tolerance Messaging
- Support remote wakeup function
- Support Intel Power Optimizer
- Support Windows Connected Standby
- Support Spread Spectrum Clock for SD to reduce EMI effect
- Support over clock of UHS-II RCLK for better read/write performance (Optional)
- Available in QFN48 pin package (6x6mm)

CHAPTER 3 Pin Assignment

3.1 QFN 48 Pinout

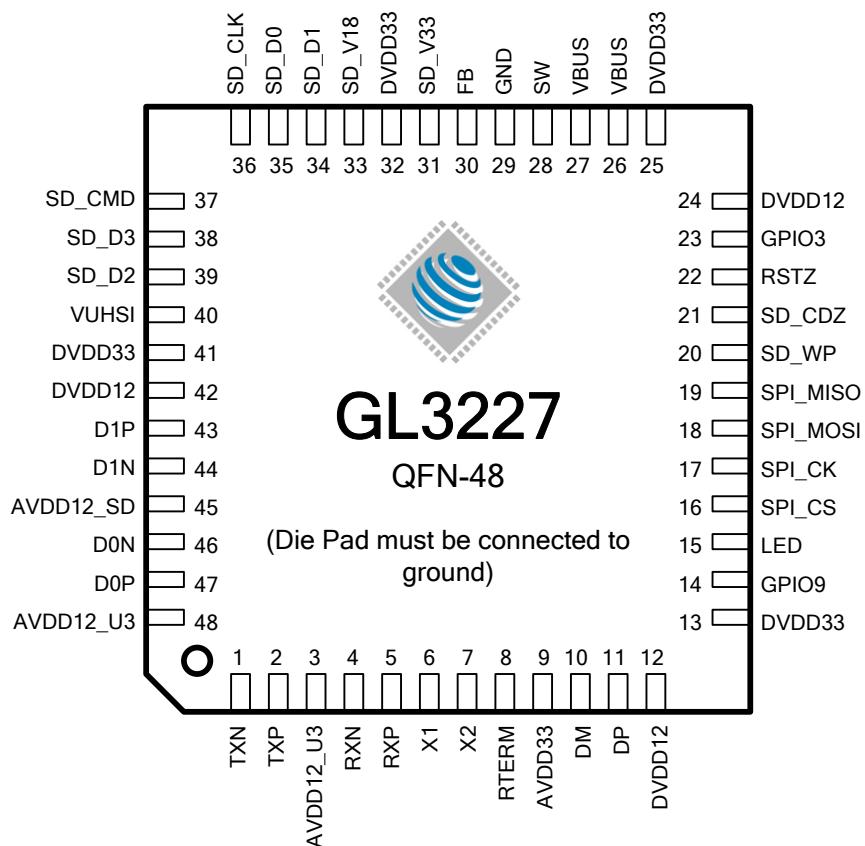


Figure 3.1 - QFN 48 Pinout Diagram

3.2 Pin Description

Table 3.1 - Pin Description

Pin Name	QFN 48 Pin	Type	Description
Power/Ground			
AVDD12_U3	3, 48	P	Analog 1.2V power source to USB 3.1 GEN1 PHY
AVDD12_SD	45	P	Analog 1.2V power source to SD
AVDD33	9	P	Analog 3.3V power source
DVDD12	12,24,42	P	Digital 1.2V power source
DVDD33	13,25,32,41	P	Digital 3.3V power source
VBUS	26, 27	P	5V power source
FB	30	P	Feedback pin, connected to 1.2V output
SW	28	P	Switch out of 5V to 1.2V DC-DC
VUHSI	40	P	UHS-I IO PAD Power, the power source of this pin comes from the internal regulator of GL3227 and no need of external power input
SD_V18	33	P	Card Power 200mA for UHS-II card only
SD_V33	31	P	Card power 600mA
GND	29	P	Ground
USB PHY Interface			
DP	11	A	USB 2.0 D+
DM	10	A	USB 2.0 D-
TXN	1	A	USB 3.1 GEN1 TX-
TXP	2	A	USB 3.1 GEN1 TX+
RXN	4	A	USB 3.1 GEN1 RX-
RXP	5	A	USB 3.1 GEN1 RX+
RTERM	8	A	USB reference resistor. This pin is used to control the level of USB signal. A 680ohm, 1% resistor is recommended to be populated between RTERM and GND
X1	6	I	25MHz XTAL input. It can be connected to external 25MHz clock input
X2	7	B	25MHz XTAL output
Memory Card Interface			
D1P	43	A	UHS-II D1+
D1N	44	A	UHS-II D1-
D0N	46	A	UHS-II D0-
D0P	47	A	UHS-II D0+
SD_CDZ	21	I, pu	SD card detect 0: Card insert 1: No card Internal pull-up to DVDD33(3.3V)
SD_D1	34	B	SD_DATA1/ RCLKON(UHS-II Clock Output)

SD_D0	35	B	SD_DATA0/ RCLKOP(UHS-II Clock Output)
SD_CLK	36	O	SD clock
SD_CMD	37	B	SD command/response
SD_D3	38	B	SD_DATA3
SD_D2	39	B	SD_DATA2
SD_WP	20	I, pu	SD write protect 0: write enable 1: write protection Internal pull-up to DVDD33(3.3V)
Others			
LED	15	O	Card Access LED
SPI_CS	16	O	SPI interface: chip select
SPI_CK	17	O	SPI interface: clock
SPI_MOSI	18	O	SPI interface: connect to SPI flash data input
SPI_MISO	19	I	SPI interface: connect to SPI flash data output
RSTZ	22	I, pu	Chip reset, active low Internal pull-up to DVDD33(3.3V)
GPIO	14,23	B	General purpose I/O

Notation:

Type	O	Output
	I	Input
	B	Bi-directional
	pu	internal pull-up when input
	pd	internal pull-down when input
	P	Power / Ground
	A	Analog

CHAPTER 4 Block Diagram

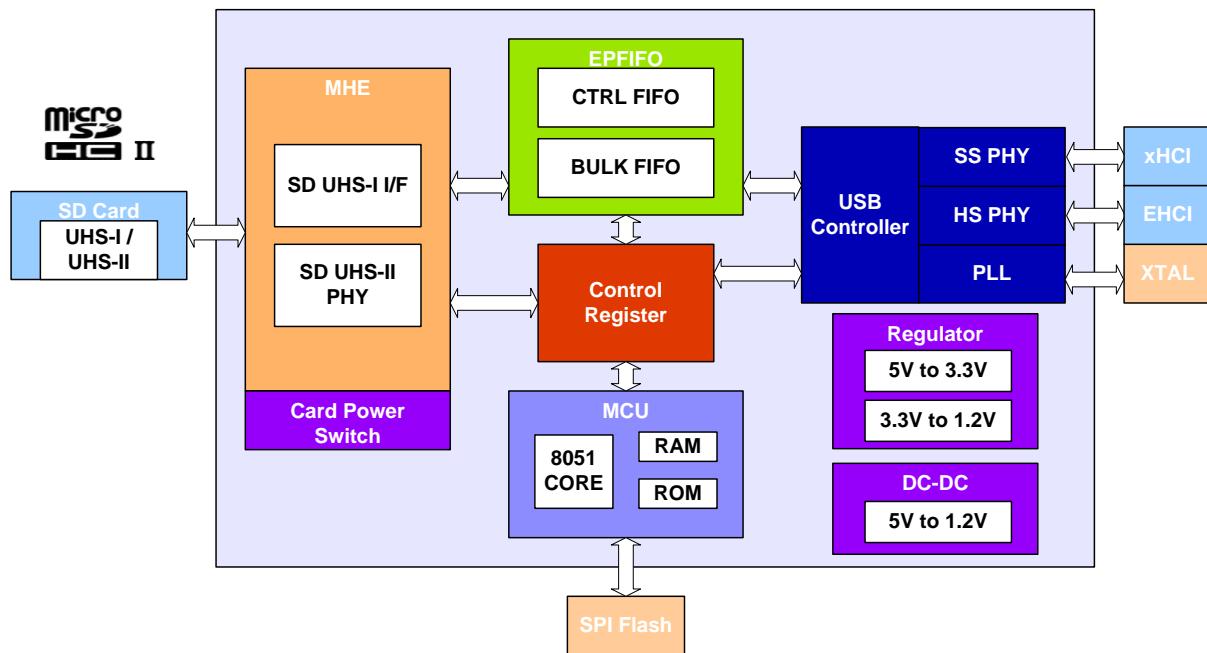


Figure 4.1 - Functional Block Diagram

4.1 Super Speed and HS PHY

The transceiver macro is the analog circuitry that handles the low level USB protocol and signaling, and shifts the clock domain of the data from the USB to one that is compatible with the general logic.

4.2 USB Controller

The USB Controller, which contains the USB PID and address recognition logic, and other sequencing and state machine logic to handle USB packets and transactions.

4.3 EPFIFO

Endpoint FIFO includes Control FIFO (FIFO0) and Bulk In/Out FIFO

- **CTRL FIFO** FIFO of control endpoint 0. It is 512-byte FIFO and used for endpoint 0 data transfer.
- **Bulk In/Out FIFO** It can be in the TX mode or RX mode:
 1. It can be transmit/receive 512-byte data of USB 2.0 and 1K-byte data of USB 3.1 GEN1 continuously.
 2. It can be directly accessed by micro-controller

4.4 MCU

8051 micro-controller inside.

- **8051 Core** Compliant with Intel 8051 high speed micro-controller
- **ROM** Firmware code on ROM
- **RAM** Internal RAM area for MCU access

4.5 MHE (Media Hardware Engine)

Media Interface: SD/MMC

4.6 Regulator

- **5V to 3.3V** 3.3V Power Source
- **3.3V to 1.2V** 1.2V Power Source

4.7 DC-DC

- **5V to 1.2V** 1.2V Power Source to analog

4.8 UHS-II PHY

The UHS-II PHY Layer handles the low level UHS-II protocol and signal.

CHAPTER 5 ELECTRICAL CHARACTERISTICS

5.1 Temperature Conditions

Table 5.1 - Temperature Conditions

Parameter	Value
Storage Temperature	-65°C to +150 °C
Operating Temperature	0°C to +70 °C

5.2 Operating Conditions

Table 5.2 - Operating Conditions

Parameter	Value
Supply Voltage	+4.75V to +5.25V
Ground Voltage	0V
Fosc (Oscillator or Crystal Frequency)	25 MHz ± 0.03%

5.3 DC Characteristics

Table 5.3 - DC Characteristics

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
V ₁₂	Output Voltage	DC-DC mode	1.17	1.28	1.40	V
V _{CC}	Supply Voltage		4.75	5.0	5.25	V
V _{IH}	Input High Voltage		2.0			V
V _{IL}	Input Low Voltage				0.4	V
I _I	Input Leakage Current	0 < V _{IN} < DVDD	-10		10	µA
V _{OH}	Output High Voltage	DVDD = 3.3V	2.8			V
V _{OL}	Output Low Voltage				0.4	V
I _{OH}	Output Current High			8		mA
I _{OL}	Output Current Low			8		mA
C _{IN}	Input Pin Capacitance			5		pF
*I _{NORMAL}	HS mode			35		mA
	SS mode	U0 state		46		mA
		U1 state		14		mA
		U2 state		9.8		mA
*I _{ACTIVE}	HS mode			46		mA
	SS mode	U0 state		55		mA

I _{RESET}				42		mA
I _{SUS}	HS Suspend current	1.5K pull-up included		0.80		mA
	SS Suspend current	U3 State		0.63		mA
R _{pu}	Reset Pad pull-up			46		KΩ
	SD_CDZ, SD_WP, GPIO Pad pull-up			46		KΩ
	SD_CMD pull-up			15		KΩ
	SD_CLK, D[3:0] Pad pull-up			15		KΩ
R _{pd}	SD_CMD pull-down			15		KΩ
	SD_CLK, D[3:0] Pad pull-down			15		KΩ
R _{IMP}	SD_CMD, SD_CLK, D[3:0] impedances			50		Ω

* I_{NORMAL}: The memory card is inserted but not in read/write

* I_{ACTIVE}: The memory card is in read/write

5.4 AC Characteristics of Reset Timing

5.4.1 Reset Timing

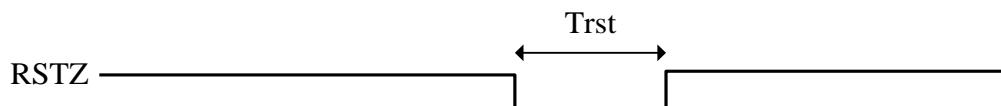


Figure 5.1 - Timing Diagram of Reset Width

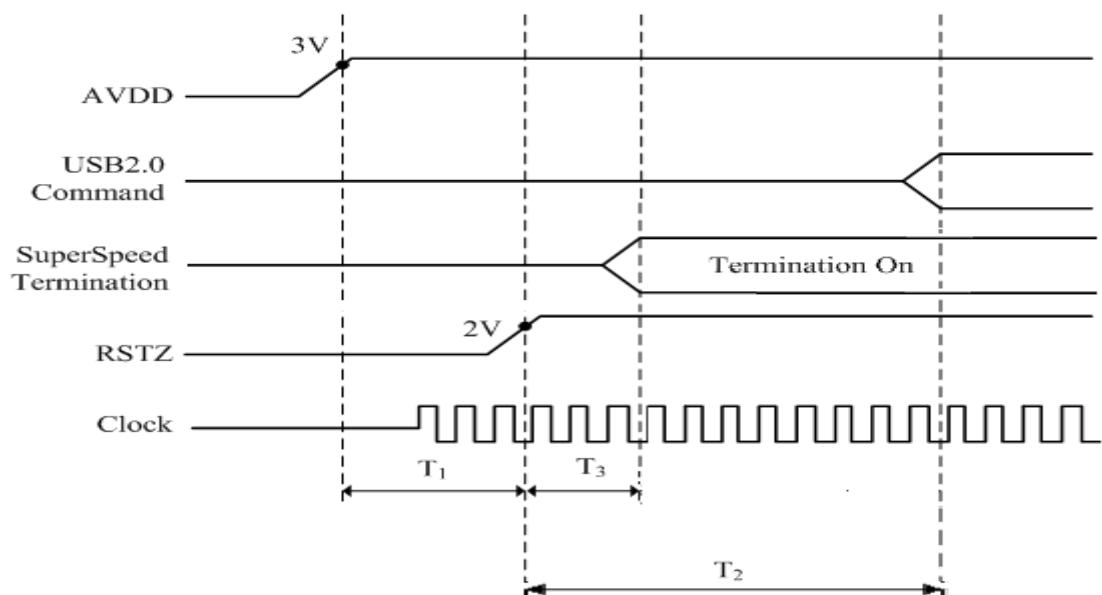


Figure 5.2 - Timing Diagram of Power-on to USB Bus Ready

Table 5.4 - Reset Timing

Parameter	Description	Min.	Max.	Unit
Trst	Chip reset sense timing width	2		us
T1	AVDD power up to reset de-assert	500		us
T2	Reset de-assert to respond USB2.0 command ready		100	ms
T3	Reset de-assert to SuperSpeed termination on		35	ms

5.4.2 SD Card Clock Frequency

Table 5.5 - SD Card Clock Frequency

Parameter	Description	Max.	Unit
F _{ID}	Clock frequency Identification Mode	187	KHz
F _{DS}	Clock frequency Default Speed Mode	25	MHz
F _{HS}	SD Clock frequency High Speed Mode	50	MHz
F _{HS}	MMC Clock frequency High Speed Mode	52	MHz
F _{SDR25}	Clock frequency UHS-I Mode: SDR25	50	MHz
F _{DDR50}	Clock frequency UHS-I Mode: DDR50	50	MHz
F _{SDR50}	Clock frequency UHS-I Mode: SDR50	100	MHz
F _{SDR104}	Clock frequency UHS-I Mode: SDR104	208	MHz
F _{RCLK52}	Clock frequency UHS-II Mode: Up to 1.56Gbps	52	MHz
UHS-II O/C	UHS-II RCLK Over Clock	57	MHz

5.5 IC ESD/LU Level

Table 5.6 - IC ESD/LU Level

Test Mode and Trigger Mode	Value
ESD HBM	± 4KV
ESD CDM	± 500V
ESD MM	± 200V
Latch-up	± 500mA

5.6 Thermal information

Table 5.7 - Thermal information (QFN48)

Ambient Temp (T _a)	Power (P)	Thermal Resistance (Θ _{ja})	Thermal Resistance (Θ _{jc})	Junction Temp (T _j)	Case Temp (T _c)
70°C	0.350W	33.64°C/W	5.06°C/W	81.8°C	80.0°C

CHAPTER 6 SPI NOR Flash Support List

Table 6.1 - SPI NOR Flash Support List

Vendor	Model
GigaDevice	GD25D10B, GD25Q20, GD25Q40, GD25Q21B, GD25Q20C
PMC	PM25LD010, PM25LD020, PM25LD010C, PM25LD020C, PM25LQ020
WINBOND	W25X10CL, W25X20CL, W25X10BV, W25X20BV, W25Q40BL
MXIC	MX25L1006E, MX25L4006E, MX25L1021E, MX25L2006E, MX25V1006F
ESMT	F25L01PA(86P), F25L01PA(100P)
FMSH	FM25F01, FM25F005, FM25F04A
EON	EN25F10, EN25LF10, EN25F40
PEA	T25S40A
Boya	BY25Q10A, BY25Q20A
XTX	FT25H04, FT25LX04
Puya	P25Q21H

Note :

- GL3227 supports Page-Program SPI Flash only, not for Byte-program SPI Flash
- Firmware file (xxxx.bin) which provided by Genesys Logic is only used for Genesys Logic's Multi-Tool and MP Tool ISP (In System Programming via USB interface) purpose. If you would like to provide FW for SPI Flash vendor mass production or Flash ROM writer, please contact GL technical support team.

CHAPTER 7 Package Dimension

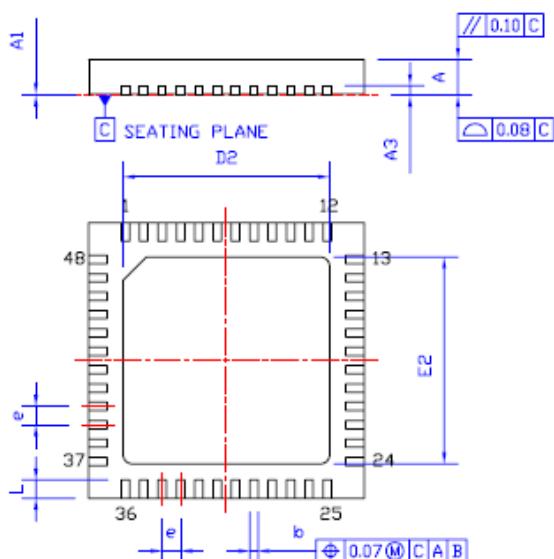
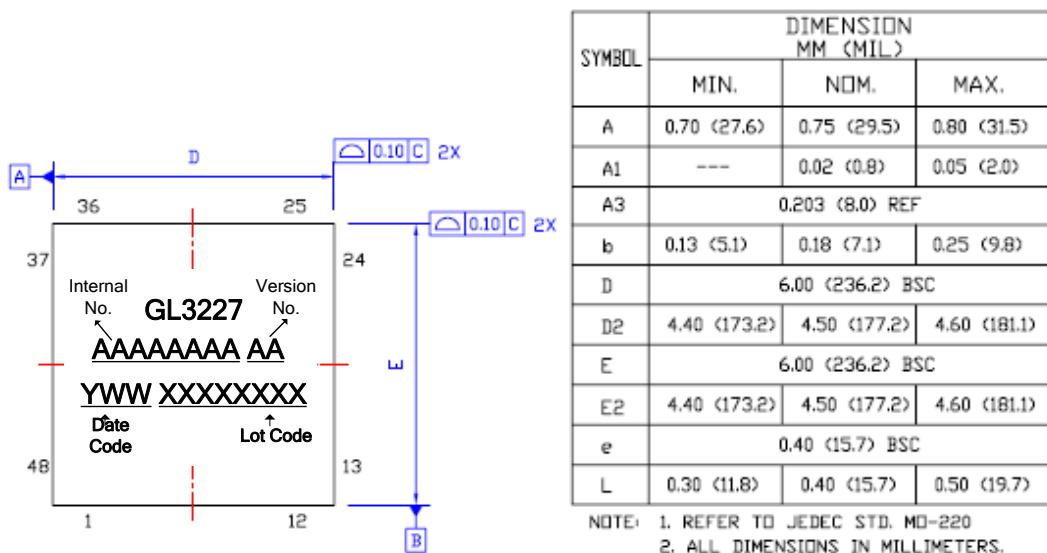


Figure 7.1 - QFN 48 Pin Package

CHAPTER 8 ORDERING INFORMATION

Table 8.1 - Ordering Information

Part Number	Package	Green/Wire Material	Version	Status
GL3227-ONYXX	QFN 48	Green Package + CU Wire	XX	MP